FC654601

Silicon N-channel MOS FET

For switching circuits

Overview

 $FC654601 \ is \ N\text{-channel dual type small signal MOS FET employed small size surface mounting package.}$

■ Features

• Low drain-source ON resistance: $R_{DS(on)}$ typ. = 6 Ω (V_{GS} = 4.0 V)

• High-speed switching

• Small size surface mounting package: SMini6-F3-B

• Contributes to miniaturization of sets, reduction of component count.

• Eco-friendly Halogen-free package

Packaging

FC6546010R Embossed type (Thermo-compression sealing): 3000 pcs / reel (standard)

■ Absolute Maximum Ratings $T_a = 25$ °C

	Parameter	Symbol	Rating	Unit
FET1 FET2	Drain-source surrender voltage	$V_{ m DSS}$	60	V
	Gate-source surrender voltage	V_{GSS}	±12	V
	Drain current	I_{D}	100	mA
	Peak drain current	I_{DP}	200	mA
Overall	Total power dissipation	P_{T}	150	mW
	Channel temperature	T _{ch}	150	°C
	Storage temperature	T _{stg}	-55 to +150	°C

■ Package

• Code

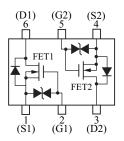
SMini6-F3-B

Package dimension clicks here.→

• Pin Name

■ Marking Symbol: V6

■ Internal Connection



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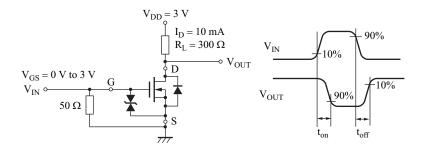
FC654601 Panasonic

■ Electrical Characteristics $T_a = 25$ °C±3°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source surrender voltage	V _{DSS}	$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}$	60			V
Drain-source cutoff current	I _{DSS}	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$			1.0	μΑ
Gate-source cutoff current	I_{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0 \text{ V}$			±10	μΑ
Gate threshold voltage	V _{TH}	$I_D = 1.0 \mu A, V_{DS} = 3.0 \text{ V}$	0.9	1.2	1.5	V
Drain-source ON resistance	R _{DS(on)}	$I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$		8	15	Ω
Diani-source On Tesistance		$I_D = 10 \text{ mA}, V_{GS} = 4.0 \text{ V}$		6	12	Ω
Forward transfer admittance	Y _{fs}	$I_D = 10 \text{ mA}, V_{DS} = 3.0 \text{ V}$	20	60		mS
Short-circuit input capacitance (Common source)	C _{iss}			12		pF
Short-circuit output capacitance (Common source)	C _{oss}	$V_{DS} = 3 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		7		pF
Reverse transfer capacitance (Common source)	C _{rss}			3		pF
Turn-on time *	t _{on}	$V_{DD} = 3 \text{ V}, V_{GS} = 0 \text{ V to 3 V},$ $I_D = 10 \text{ mA}$		100		ns
Turn-off time *	t _{off}	$V_{DD} = 3 \text{ V}, V_{GS} = 3 \text{ V to } 0 \text{ V},$ $I_D = 10 \text{ mA}$		100		ns

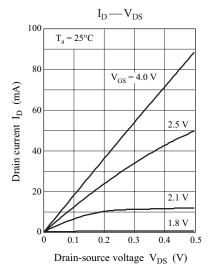
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

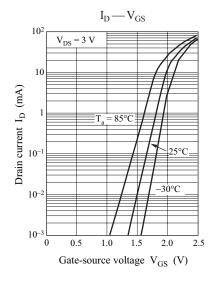
2. *: Test circuit

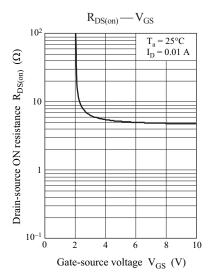


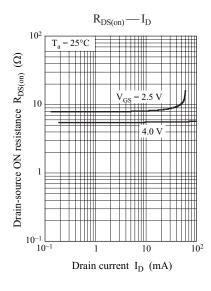
2 Ver. BED

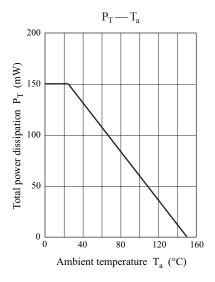
Panasonic FC654601

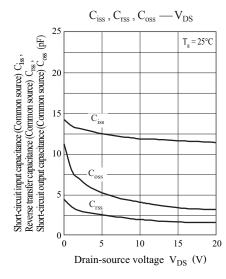


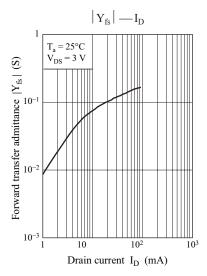












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